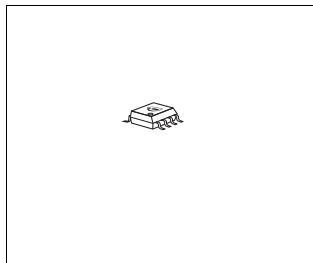




Features

- Adjustable constant output current
- Wide input voltage range
- Low drop voltage
- Open load detection
- Overtemperature protection
- Short circuit proof
- Reverse polarity proof
- Wide temperature range: $-40\text{ °C} < T_j < 150\text{ °C}$
- Very small SMD-Package
- Green Product (RoHS compliant)
- AEC Qualified



Functional Description

The **TLE4241GM** is an integrated adjustable constant current source. It provides an output current adjustable via different means (SET, PWM, reference resistor) which is kept nearly independent from load and supply voltage changes. The IC is designed to supply LEDs under the severe conditions of automotive applications resulting in constant brightness and extended LED lifetime. It is provided in the very small P-DSO-8-9 (Micro 8) package. Protection circuits prevent damage to the device in case of overload, short circuit, reverse polarity and overtemperature. The connected LEDs are protected against reverse polarity as well as excess voltages up to 45 V. A status output allows handling of open load and short circuit at the main output.

A PWM input offers the possibility to adjust the LED brightness by pulse width modulation.

With an implemented high/low current switch the output current level can be reduced e.g. for brake/tail light application.

The implemented features such as adjustable output current, the high/low current switch and the provided PWM input make the device well suited for a broad range of LED and other applications.

Type	Package
TLE4241GM	P-DSO-8-9

Circuit Description

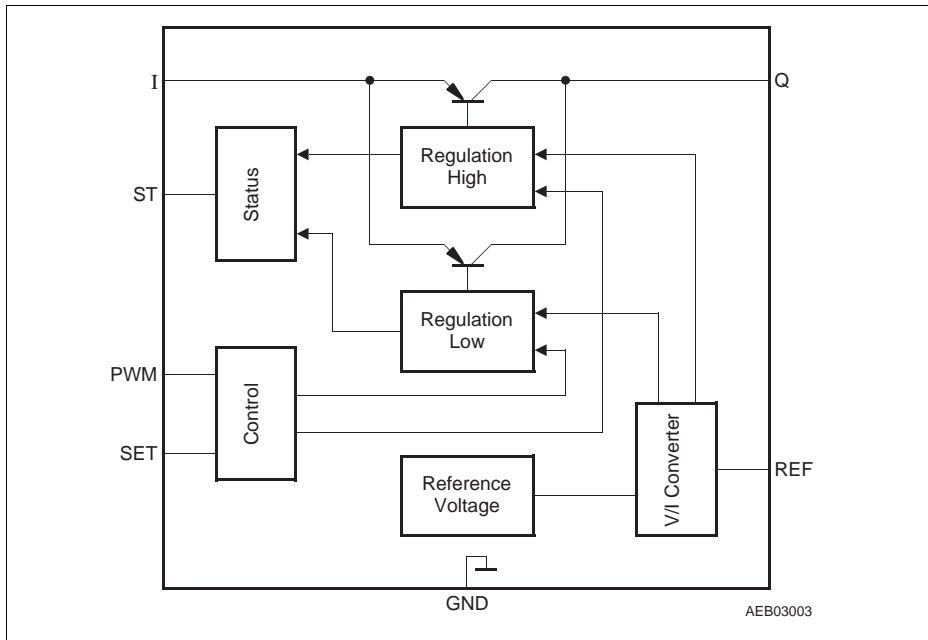


Figure 1 Block Diagram

An internal reference voltage of typ. 1.20 V supplies the REF pin which is connected to GND via an external resistor. In the SET = H mode the reference current flowing on the REF pin is mirrored with an amplification to form the desired output current. The typ. output current in the SET = H mode calculates:

$$I_{Q, \text{typ}}/\text{mA} = \frac{1.20}{R_{\text{REF}}/\text{k}\Omega} \times 487 + 0.1 \quad (1)$$

The output current is shown as a function of the reference resistance on [Page 10](#) for the high as well as for the low current mode.

With the PWM input the LED brightness can be regulated via duty cycle. Also PWM = L sets the TLE4241 in sleep mode resulting in a very low current consumption of $\ll 1 \mu\text{A}$ typ. Due to the high impedance of the PWM input (see timing diagram I_{PWM} versus V_{PWM} on [Page 12](#)) the PWM pin can thus also be used as an Enable input.

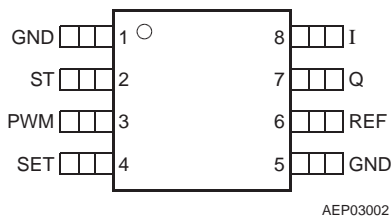


Figure 2 **Pin Configuration** (top view)

Table 1 **Pin Definitions and Functions**

Pin No.	Symbol	Function
1	GND	Ground ; internally connected to pin 5
2	ST	Status Output ; open collector output, connect to external pull-up resistor (10 k Ω or higher)
3	PWM	Pulse Width Modulation Input ; if not needed connect to V_I
4	SET	High/Low Current Input ; choice of current level
5	GND	Ground ; internally connected to pin 1
6	REF	Reference Input ; connect to GND via an external resistor to adjust the output current
7	Q	Output
8	I	Input ; block to GND directly at the IC with a 100 nF ceramic capacitor

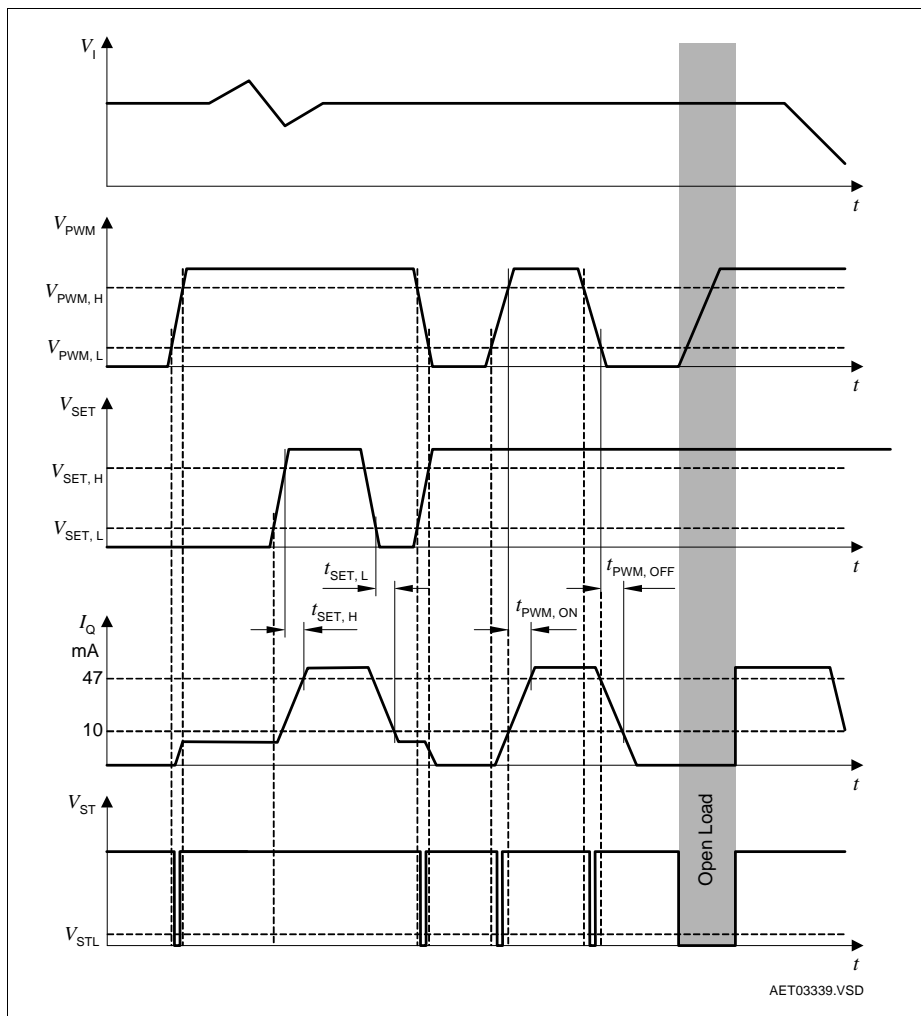


Figure 4 Function and Timing Diagram

Table 2 Absolute Maximum Ratings
 $-40\text{ }^{\circ}\text{C} < T_j < 150\text{ }^{\circ}\text{C}$

Parameter	Symbol	Limit Values		Unit	Remarks
		Min.	Max.		
Input					
Voltage	V_I	-42	45	V	–
Current	I_I	–	–	mA	internally limited
Output					
Voltage	V_Q	-1	40	V	–
Current	I_Q	–	–	mA	internally limited
Status Output					
Voltage	V_{ST}	-0.3	40	V	–
Current	I_{ST}	– 5	5	mA	internally limited
Reference Input					
Voltage	V_{REF}	-0.3	7	V	–
Current	I_{REF}	-2	2	mA	–
Pulse Width Modulation Input					
Voltage	V_{PWM}	-40	40	V	–
Current	–	-1	1	mA	–
High/Low Current Input					
Voltage	V_{SET}	-40	40	V	–
Current	I_{SET}	-1	1	mA	–
Temperatures					
Junction temperature	T_j	-40	150	°C	–
Storage temperature	T_{stg}	-50	150	°C	–
Thermal Resistances					
Junction ambient	R_{thja}	–	105	K/W	1)

1) Worst case regarding peak temperature; mounted on PCB $80 \times 80 \times 1.5\text{ mm}^3$, $35\text{ }\mu\text{m Cu}$, 300 mm^2 heat sink area.

Note: Maximum ratings are absolute ratings; exceeding any one of these values may cause irreversible damage to the integrated circuit.

Table 3 Operating Range

Parameter	Symbol	Limit Values		Unit	Remarks
		Min.	Max.		
Input voltage	V_I	4	45	V	–
Status output voltage	V_{ST}	–	16	V	–
SET voltage	V_{SET}	0	40	V	–
PWM voltage	V_{PWM}	0	40	V	–
Junction temperature	T_j	-40	150	°C	–
Reference Resistor	R_{REF}	7	100	kΩ	SET = H
		4.7	18	kΩ	SET = L

Table 4 Electrical Characteristics

$9\text{ V} \leq V_I \leq 16\text{ V}$; $R_{\text{REF}} = 10\text{ k}\Omega$; $V_{\text{PWM}} \geq V_{\text{PWM,H}}$; $-40\text{ }^\circ\text{C} < T_J < 150\text{ }^\circ\text{C}$; all voltages with respect to ground; positive current defined flowing into pin; unless otherwise specified

Parameter	Symbol	Limit Values			Unit	Test Condition
		Min.	Typ.	Max.		
Current consumption off mode	I_{qOFF}	–	0.1	4	μA	$\text{PWM} = \text{L}$, $T_J < 85\text{ }^\circ\text{C}$; $V_I \leq 13.5\text{ V}$
Current consumption	I_{qL}	–	4	7	mA	$\text{SET} = \text{L}$; $V_Q = 6\text{ V}$
Current consumption	I_{qH}	–	5	7	mA	$\text{SET} = \text{H}$; $V_Q = 6\text{ V}$
Current consumption open load	$I_{\text{qL,O}}$	–	–	8	mA	$\text{SET} = \text{L}$; V_Q open
Current consumption open load	$I_{\text{qH,O}}$	–	–	8	mA	$\text{SET} = \text{H}$; V_Q open

Output

Output current	I_Q	7	8.4	9.5	mA	$\text{SET} = \text{L}$, $V_Q = 6\text{ V}$
		–	8.6	–	mA	$\text{SET} = \text{L}$, $V_Q = 4\text{ V}$
Output current	I_Q	50	58.5	65	mA	$\text{SET} = \text{H}$, $V_Q = 6\text{ V}$
		–	60.0	–	mA	$\text{SET} = \text{H}$, $V_Q = 4\text{ V}$
Current Ratio	$I_{\text{QH}}/I_{\text{QL}}$	6	7	8	–	–
Output current limit	I_{Qmax}	–	83	–	mA	$\text{SET} = \text{L}$; $R_{\text{REF}} = 0\text{ }\Omega$
Output current limit	I_{Qmax}	–	83	–	mA	$\text{SET} = \text{H}$; $R_{\text{REF}} = 0\text{ }\Omega$
Drop voltage	V_{dr}	–	0.2	0.5	V	$\text{SET} = \text{L}$; $I_Q = 80\%$ of $I_{\text{Q,nom,L}}$
Drop voltage	V_{dr}	–	0.3	0.5	V	$\text{SET} = \text{H}$; $I_Q = 80\%$ of $I_{\text{Q,nom,H}}$

PWM Input

PWM high level	$V_{\text{PWM,H}}$	2.0	–	–	V	–
PWM low level	$V_{\text{PWM,L}}$	–	–	0.5	V	–
PWM input current high level	$I_{\text{PWM,H}}$	–	220	500	μA	$V_{\text{PWM}} = 5.0\text{ V}$
PWM input current low level	$I_{\text{PWM,L}}$	-10	–	10	μA	$V_{\text{PWM}} = 0.0\text{ V}$
Turn on delay time	$t_{\text{PWM,ON}}$	0	5	30	μs	20%/80% I_Q , see Figure 4

Table 4 Electrical Characteristics (cont'd)

$9\text{ V} \leq V_I \leq 16\text{ V}$; $R_{\text{REF}} = 10\text{ k}\Omega$; $V_{\text{PWM}} \geq V_{\text{PWM,H}}$; $-40\text{ }^{\circ}\text{C} < T_j < 150\text{ }^{\circ}\text{C}$; all voltages with respect to ground; positive current defined flowing into pin; unless otherwise specified

Parameter	Symbol	Limit Values			Unit	Test Condition
		Min.	Typ.	Max.		
Turn off delay time	$t_{\text{PWM,OFF}}$	0	10	30	μs	20%/80% I_Q , see Figure 4

SET Input

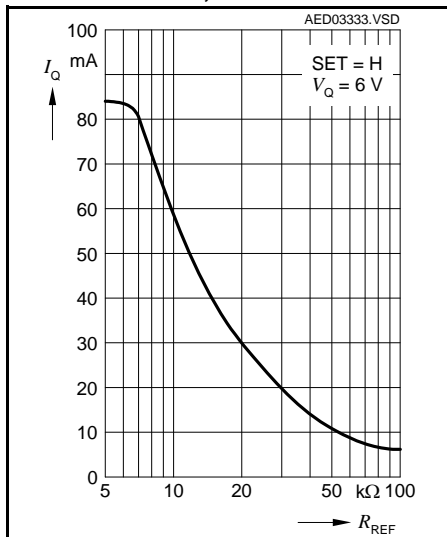
SET high level	$V_{\text{SET,H}}$	2.0	–	–	V	–
SET low level	$V_{\text{SET,L}}$	–	–	0.5	V	–
SET input current high level	$I_{\text{SET,H}}$	–	220	500	μA	$V_{\text{SET}} = 5.0\text{ V}$
SET input current low level	$I_{\text{SET,L}}$	-10	–	10	μA	$V_{\text{SET}} = 0.0\text{ V}$
Delay time L -> H	$t_{\text{SET,H}}$	–	–	30	μs	20%/80% I_Q , see Figure 4
Delay time H -> L	$t_{\text{SET,L}}$	–	–	30	μs	20%/80% I_Q , see Figure 4

Status Output

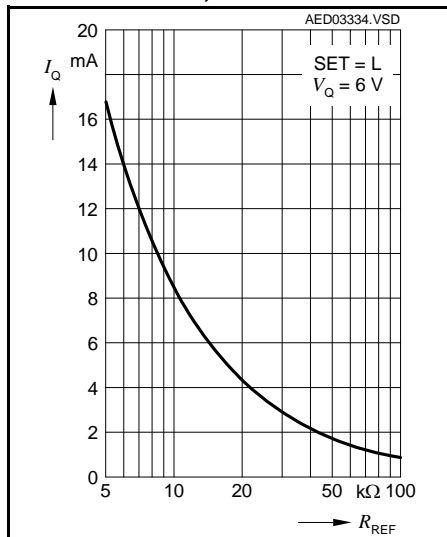
Lower status switching threshold	$V_{\text{dr,L}}$	0.15	–	–	V	$(V_I - V_Q)$ decreasing SET = L
		0.15	–	–	V	$(V_I - V_Q)$ decreasing SET = H
Upper status switching threshold	$V_{\text{dr,H}}$	–	–	0.7	V	$(V_I - V_Q)$ increasing SET = L
		–	–	0.7	V	$(V_I - V_Q)$ increasing SET = H
Status low voltage	V_{STL}	–	–	0.4	V	$(V_I - V_Q) < V_{\text{dr,L}}$ $I_{\text{ST}} = 1.0\text{ mA}$
Leakage current	I_{STLK}	–	–	10	μA	$(V_I - V_Q) > V_{\text{dr,H}}$ $V_{\text{ST}} = 5.0\text{ V}$

Typical Performance Characteristics

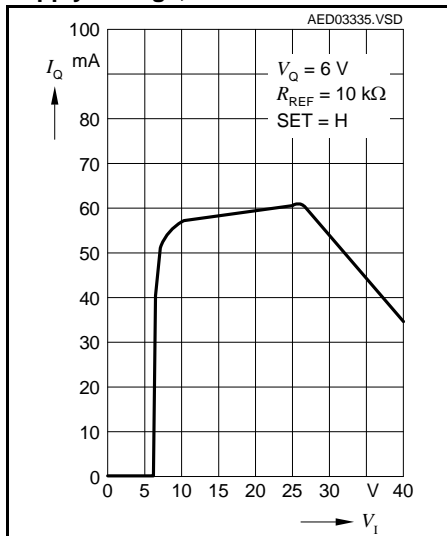
**Output Current versus
External Resistor, SET = H**



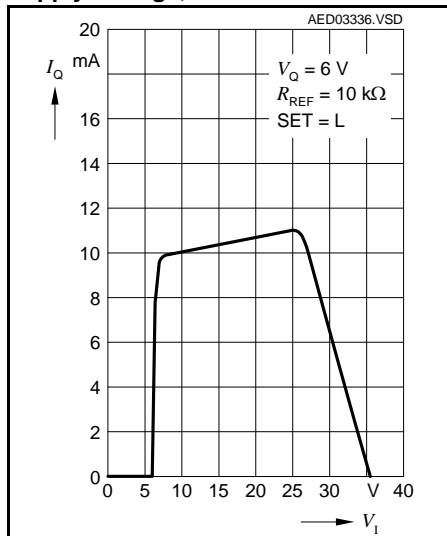
**Output Current versus
External Resistor, SET = L**



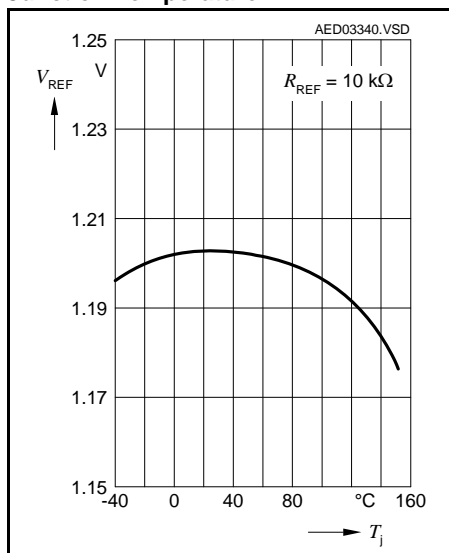
**Output Current versus
Supply Voltage, SET = H**

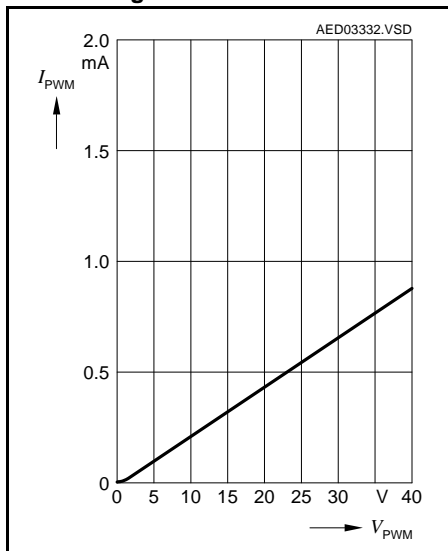
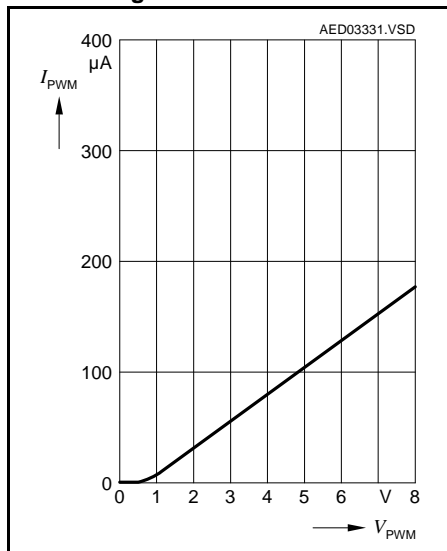
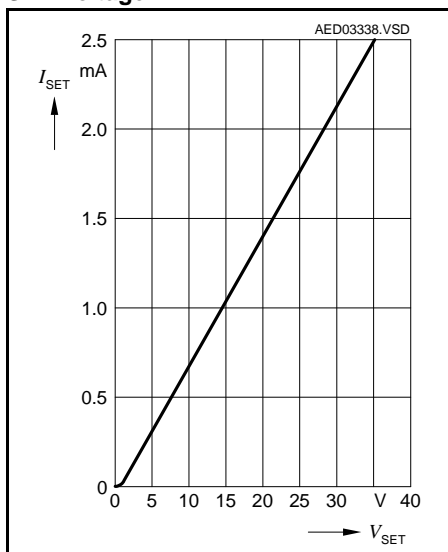
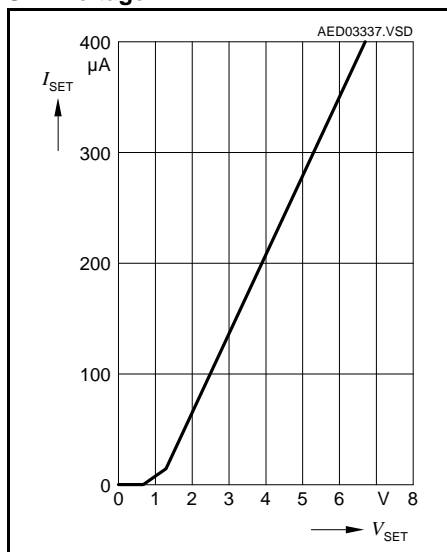


**Output Current versus
Supply Voltage, SET = L**



Reference Voltage versus Junction Temperature



PWM Pin Input Current versus PWM Voltage

PWM Pin Input Current versus PWM Voltage

SET Pin Input Current versus SET Voltage

SET Pin Input Current versus SET Voltage


Package Outlines

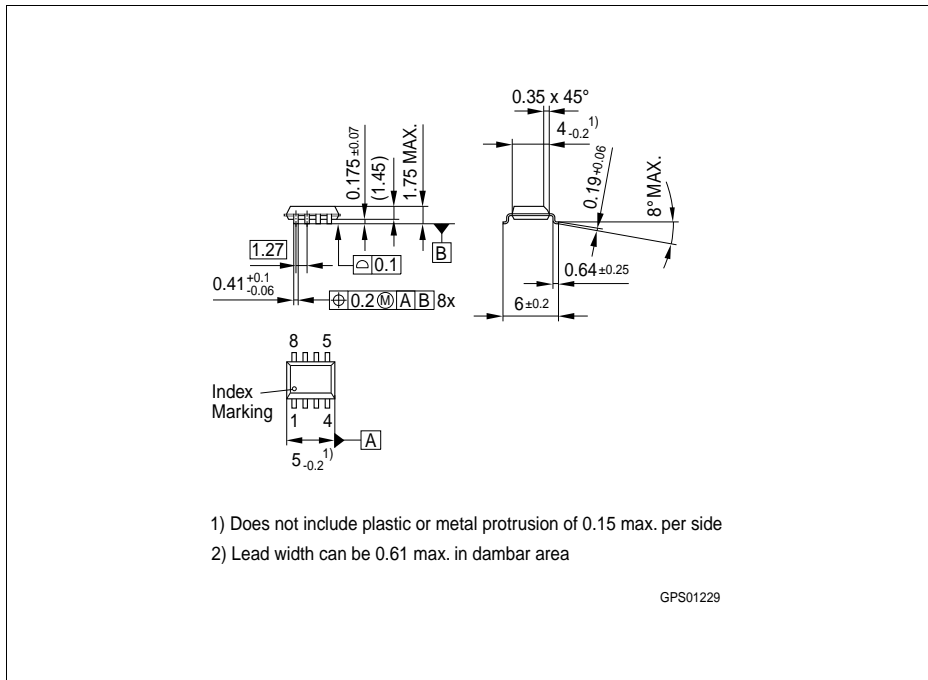


Figure 5 **P-DSO-8-9** (Plastic Dual Small Outline)

Green Product (RoHS compliant)

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).

You can find all of our packages, sorts of packing and others in our Infineon Internet Page "Products": <http://www.infineon.com/products>.

SMD = Surface Mounted Device

Dimensions in mm

Revision History

Version	Date	Changes
Rev. 1.2	2004-04-13	Page 4, 9: Improved indication and explanation of the open load detection function.
Rev. 1.3	2007-03-19	Initial version of RoHS-compliant derivate of TLE4241GM Page 1 : AEC certified statement added Page 1 and Page 13 : RoHS compliance statement and Green product feature added Page 1 and Page 13 : Package changed to RoHS compliant version Legal Disclaimer updated
Rev. 1.4	2015-07-09	Electrical Characteristics updated Page 8

Edition 2015-10-05

**Published by
Infineon Technologies AG
81726 Munich, Germany**

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